



# EMIF02-SPK01C2

IPAD™

2 line EMI filter and ESD protection

## Main product characteristics

Where EMI filtering in ESD sensitive equipment is required:

- Mobile phones and communication systems
- Computers and printers and MCU Boards

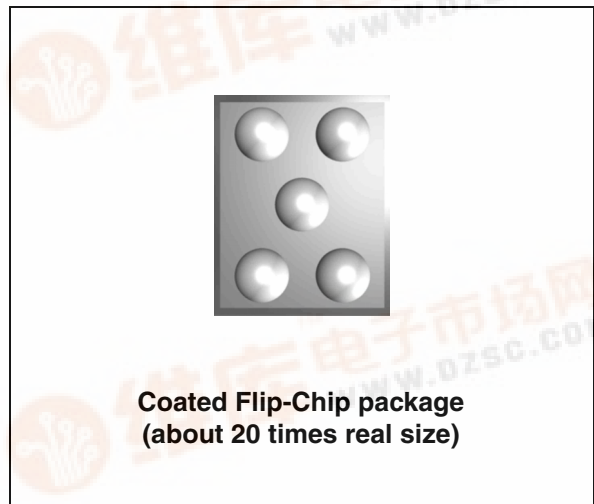
## Description

The EMIF02-SPK01C2 is a highly integrated device designed to suppress EMI/RFI noise in all systems subjected to electromagnetic interference. The Flip-Chip packaging means the package size is equal to the die size.

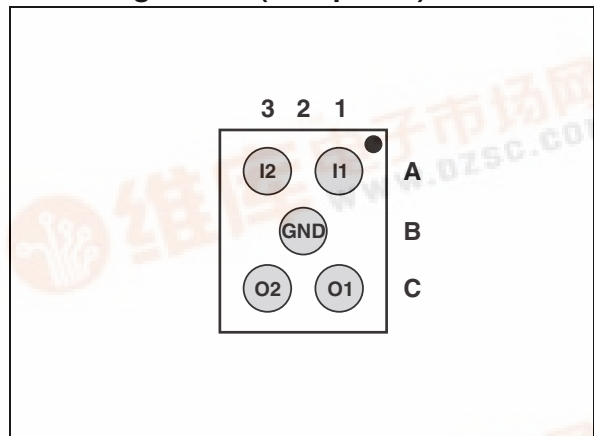
This filter includes ESD protection circuitry, which prevents damage to the application when it is subjected to ESD surges up to 15 kV.

## Benefits

- EMI symmetrical (I/O) low-pass filter
- High efficiency EMI filter (-33 dB @ 900 MHz)
- Very low PCB space consumption:  
1.07 mm x 1.47 mm
- Very thin package: 0.695 mm
- Coating resin on back side and lead free package
- High efficiency in ESD suppression
- High reliability offered by monolithic integration
- High reduction of parasitic elements through integration and wafer level packaging.



## Pin configuration (Bump side)



## Complies with following standards:

### IEC 61000-4-2

|                     |       |                     |
|---------------------|-------|---------------------|
| level 4 input pins  | 15 kV | (air discharge)     |
|                     | 8 kV  | (contact discharge) |
| level 1 output pins | 2 kV  | (air discharge)     |
|                     | 2 kV  | (contact discharge) |

### MIL STD 883G - Method 3015-7 Class 3



# 1 Characteristics

Figure 1. Basic cell configuration

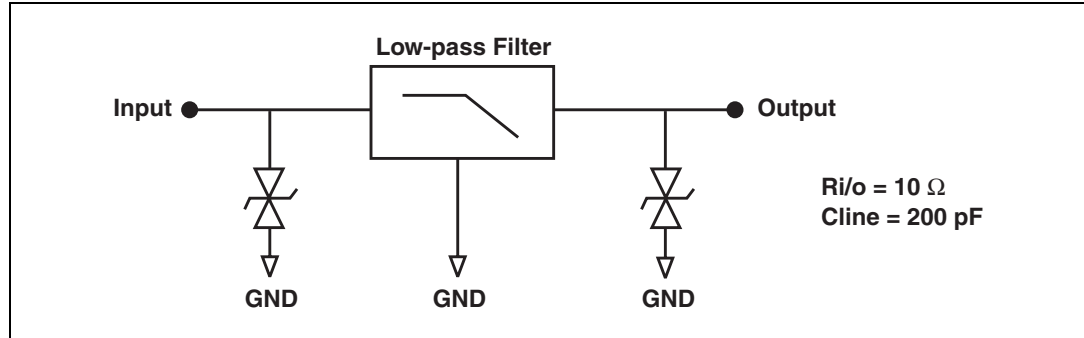


Table 1. Absolute ratings (limiting values)

| Symbol    | Parameter                    | Value       | Unit |
|-----------|------------------------------|-------------|------|
| $T_j$     | Maximum junction temperature | 125         | °C   |
| $T_{op}$  | Operating temperature range  | -40 to +85  | °C   |
| $T_{stg}$ | Storage temperature range    | -55 to +150 | °C   |

Table 2. Electrical characteristics ( $T_{amb} = 25^\circ C$ )

| Symbol     | Parameters                                 |
|------------|--|
| $V_{BR}$   | Breakdown voltage                          |
| $I_{RM}$   | Leakage current @ $V_{RM}$                 |
| $V_{RM}$   | Stand-off voltage                          |
| $V_{CL}$   | Clamping voltage                           |
| $R_d$      | Dynamic impedance                          |
| $I_{PP}$   | Peak pulse current                         |
| $R_{I/O}$  | Series resistance between input and output |
| $C_{line}$ | Input capacitance per line                 |

| Symbol     | Test conditions                 | Min | Typ | Max | Unit     |
|------------|---------------------------------|-----|-----|-----|----------|
| $V_{BR}$   | $I_R = 1 \text{ mA}$            | 6   | 8   |     | V        |
| $I_{RM}$   | $V_{RM} = 3 \text{ V per line}$ |     |     | 500 | nA       |
| $R_{I/O}$  | Tolerance $\pm 20\%$            |     | 10  |     | $\Omega$ |
| $C_{line}$ | $V_R = 0 \text{ V}$             |     | 200 |     | pF       |

Figure 2. S21 (dB) attenuation measurement

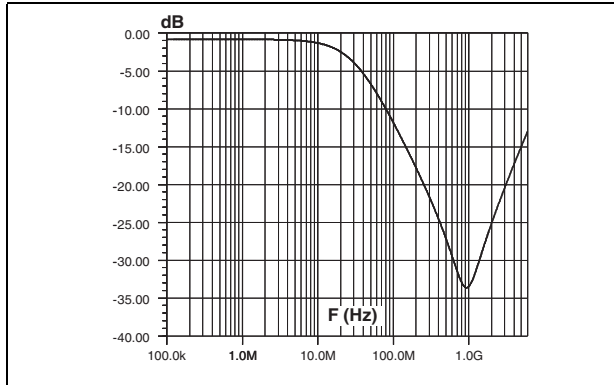


Figure 3. Analog crosstalk measurement

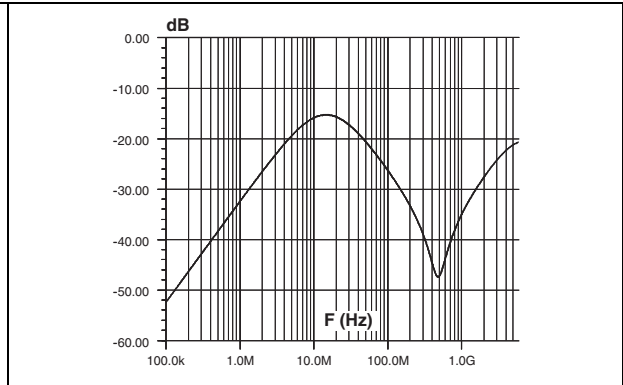


Figure 4. ESD response to IEC 61000-4-2 (+15 kV air discharge) on one input  $V_{in}$  and one output  $V_{out}$

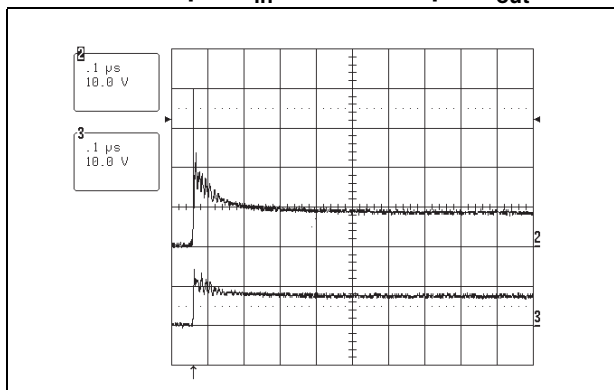


Figure 5. ESD response to IEC 61000-4-2 (-15 kV air discharge) on one input  $V_{in}$  and one output  $V_{out}$

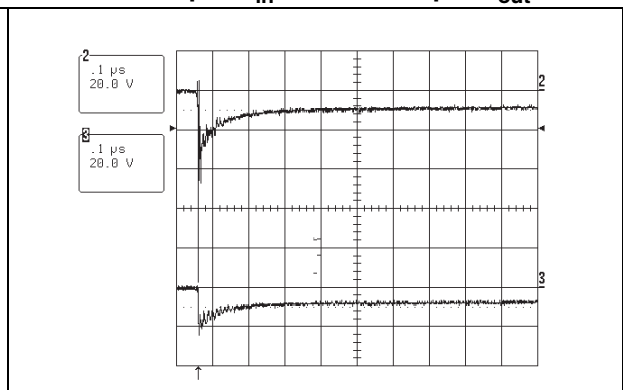
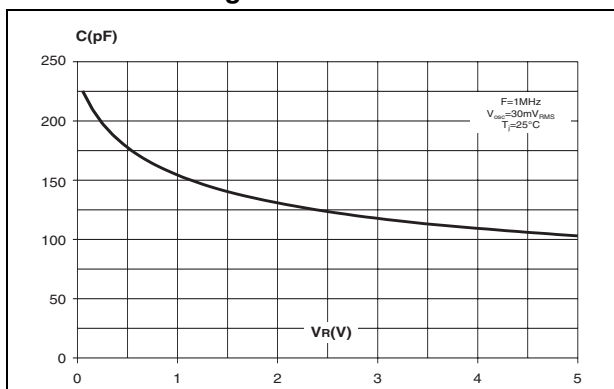
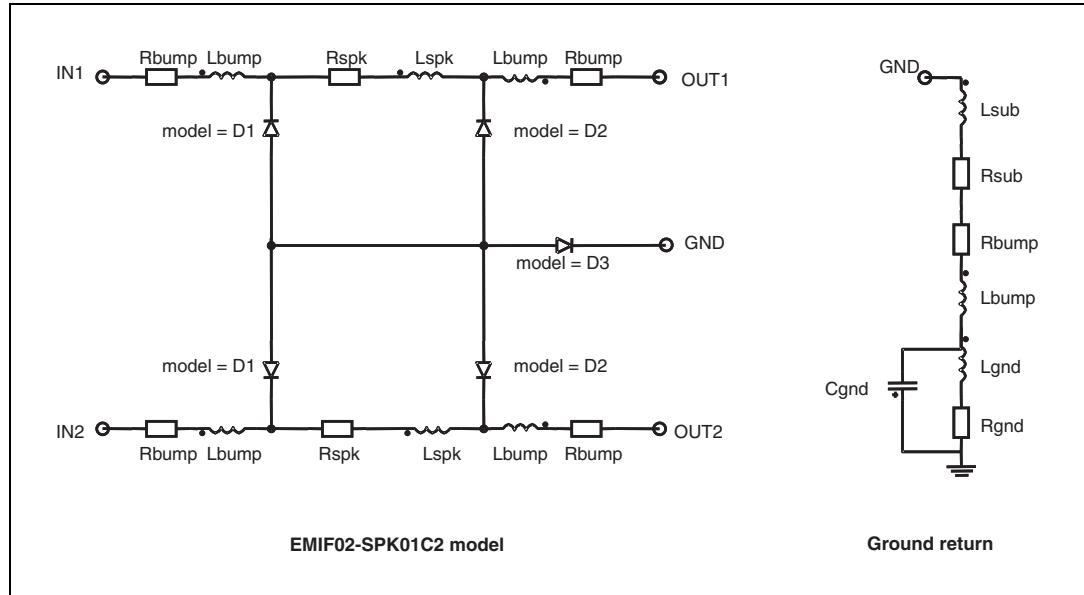


Figure 6. Line capacitance versus applied voltage



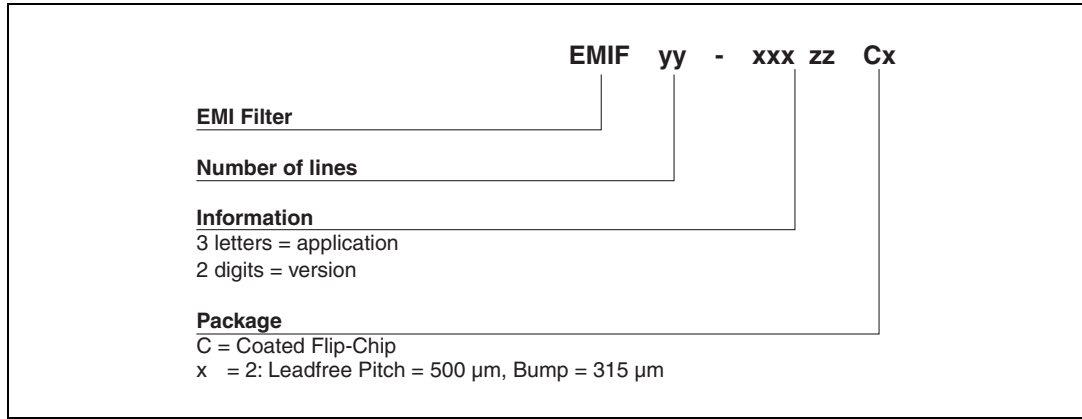
**Figure 7. Aplac model**



**Figure 8. Aplac parameters**

|             |             |             |                         |
|-------------|-------------|-------------|-------------------------|
| Model D1    | Model D3    | Model D2    | aplacvar Ls 1nH         |
| CJO=Cdiode1 | CJO=Cdiode3 | CJO=Cdiode2 | aplacvar Rs 150m        |
| BV=7        | BV=7        | BV=7        | aplacvar Rspk 10        |
| IBV=1u      | IBV=1u      | IBV=1u      | aplacvar Lspk 10p       |
| IKF=1000    | IKF=1000    | IKF=1000    | aplacvar Cdiode1 234pF  |
| IS=10f      | IS=10f      | IS=10f      | aplacvar Cdiode2 3.5ppF |
| ISR=100p    | ISR=100p    | ISR=100p    | aplacvar Cdiode3 1nF    |
| N=1         | N=1         | N=1         | aplacvar Lbump 50pH     |
| M=0.3333    | M=0.3333    | M=0.3333    | aplacvar Rbump 10m      |
| RS=0.7      | RS=0.12     | RS=0.3      | aplacvar Rsub 0.5m      |
| VJ=0.6      | VJ=0.6      | VJ=0.6      | aplacvar Lsub 10pH      |
| TT=50n      | TT=50n      | TT=50n      | aplacvar Rgnd 1m        |
|             |             |             | aplacvar Lgnd 50pH      |
|             |             |             | aplacvar Cgnd 0.15pF    |

## 2 Ordering information scheme



## 3 Package information

Figure 9. Flip-Chip Dimensions

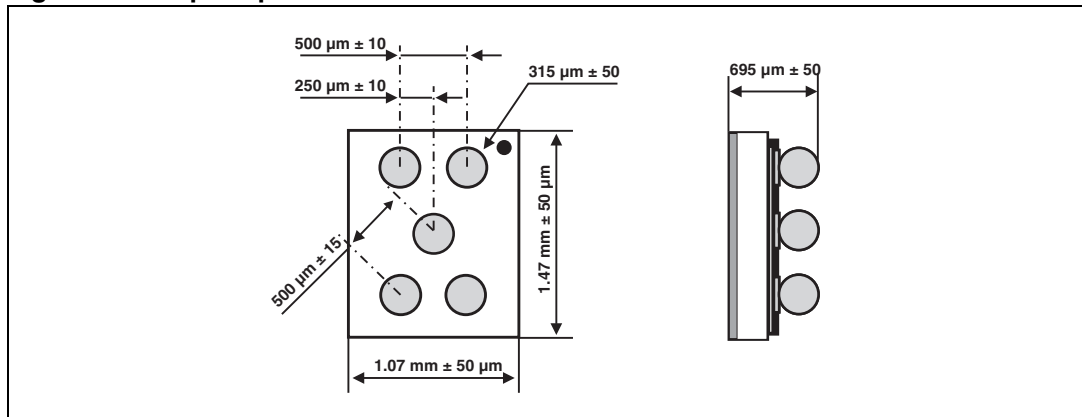


Figure 10. Marking

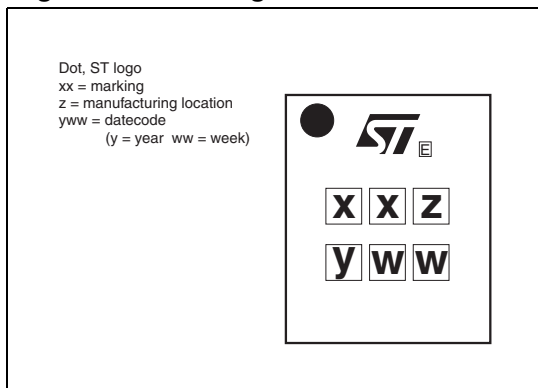


Figure 11. Footprint recommendation

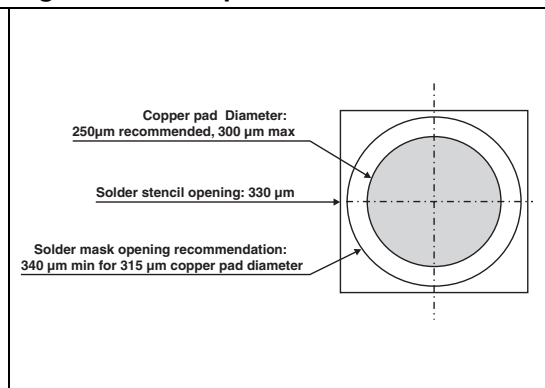
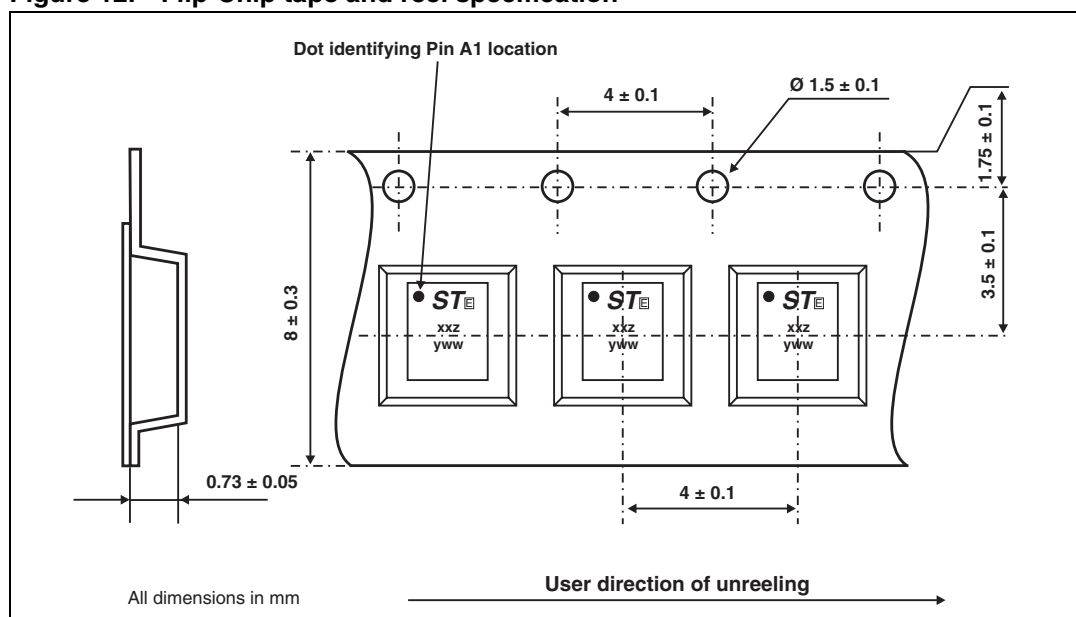


Figure 12. Flip-Chip tape and reel specification



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

## 4 Ordering information

| Ordering code  | Marking | Package   | Weight | Base qty | Delivery mode    |
|----------------|---------|-----------|--------|----------|------------------|
| EMIF02-SPK01C2 | FX      | Flip-Chip | 2.3 mg | 5000     | 7" Tape and reel |

## 5 Revision history

| Date        | Revision | Changes          |
|-------------|----------|------------------|
| 26-Jan-2006 | 1        | Initial release. |

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